

### 5.1 Electron bands in a semiconductor

A semiconductor may be described by a valence and a conduction electron energy bands, which are completely filled and empty, respectively, at  $T = 0$ . At  $T > 0$ , electrons may be excited and tunnel into the conduction band leaving behind a “hole” in the valence band. Taking the top of the valence band as zero, the electron energies in these bands are

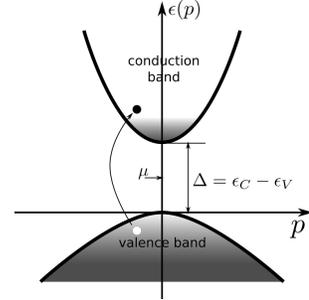
$$\epsilon_V(p) = -\frac{p^2}{2m_V}, \quad \epsilon_C(p) = \frac{p^2}{2m_C} + \Delta$$

where  $\Delta$  is the band gap, in which there are no electron energy levels, and  $m_{V,C}$  are the electron effective masses.

Consider a non-degenerate semiconductor at room temperature  $T \ll \Delta$ , in which the electron chemical potential  $\mu$  is far away from the edges of the electron bands:  $\mu \gg T$ ,  $(\Delta - \mu) \gg T$ .

(a) Assuming that the electron gas is ideal (non-interacting), calculate the densities of electrons  $n_e = N_e^{\text{cond}}/V$  in the conduction band and the number of holes  $n_h = N_h^{\text{val}}/V = (N - N_e^{\text{val}})/V$  in the valence band as functions of temperature and the chemical potential, where  $N$  is the total number of electrons.

(b) Find the equilibrium chemical potential  $\mu_i$  in the intrinsic semiconductor (i.e. without doping) and calculate the densities of holes and electrons  $n_h = n_e = n_i$ .



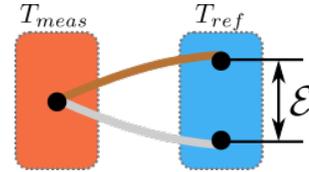
### 5.2 Thermocouple

Assuming the free ideal Fermi gas model for electrons in copper ( $\epsilon_F^{\text{Cu}} = 7.0 \text{ eV}$ ) and aluminum ( $\epsilon_F^{\text{Al}} = 11.7 \text{ eV}$ ), estimate the sensitivity

$$d\mathcal{E}/dT \approx \mathcal{E}/(T_{\text{meas}} - T_{\text{ref}})$$

of a Cu-Al thermocouple in  $[V/K]$  for room temperatures  $T_{\text{meas}}$  and  $T_{\text{ref}}$ .

*Hint: a temperature gradient in a metal leads to thermal emf because the electron chemical potential depends on temperature.*



### 5.3 Degenerate relativistic Fermi gas

Consider an ideal Fermi gas of  $N$  spin-1/2 ultrarelativistic particles with energies  $\epsilon(p) = c|p|$  confined in volume  $V$  and at zero temperature. Calculate the energy and the pressure of the relativistic gas. What is the relation between the pressure, volume, and the energy?

*Hint: start with computing the density of states  $g(\epsilon) = \frac{dN}{d\epsilon}$  as a function of the number density  $n = N/V$  and the Fermi energy  $\epsilon_F$ . You may need it in the next problem.*

### 5.4 Paramagnetism of a degenerate Fermi gas

Consider an ideal degenerate Fermi gas of spin-1/2 non-relativistic particles with magnetic moments  $\mu_z = \pm\mu$ , in a weak external magnetic field  $H\hat{z}$ ,  $\mu H \ll T$ .

(a) Calculate the magnetic moment of the unit volume of the gas due to spin alignment/antialignment with respect to the magnetic field  $H\hat{z}$ .

(b) How does the result change if the gas is ultrarelativistic?

*Hint: express the answer using the number density  $n = N/V$  and  $\epsilon_F$ .*